

AMENDMENTS TO THE CLAIMS:

This listing of claims will replace all prior versions and listings of claims in the application:

Claims 1-13 (Canceled).

Claim 14 (Currently amended): A process of fabricating a planar optical device, the process comprising:

forming a ridge structure having a ridge portion and a planar portion in a layer of a first material, said layer having a first refractive index;
depositing a core layer over the ridge structure to form an intermediate structure, the core layer comprising a core material having a second refractive index;
depositing an upper cladding layer over the intermediate structure, the upper cladding layer comprising an upper cladding material having a third refractive index;
wherein the second refractive index is greater than the first refractive index and greater than the third refractive index, and wherein the process excludes a separate step of ~~etching~~ patterning the core layer, and wherein the planar optical device is formed with ~~the a~~ core layer ~~deposition~~ deposit remaining on the ridge portion of the ridge structure.

Claim 15 (Currently Amended): The process of Claim 14 wherein depositing the core layer is comprises:

depositing the core layer by a physical vapor deposition process wherein the ridge structure is positioned opposite a target comprising the core material and radio frequency power is applied to the target at a first frequency in the presence of a gas such that a uniform plasma condition is created in the vicinity of the target, sputtering material from the target onto the ridge structure.

Claim 16 (Previously presented): The process of Claim 15 wherein depositing the core layer further comprises

applying radio frequency power to the ridge structure.

Claim 17 (Previously presented): The process of Claim 15 wherein depositing the core layer further comprises

applying radio frequency power at a second frequency to the target,
wherein the second frequency is smaller than the first frequency.

Claim 18 (Currently Amended): A process of fabricating a planar optical device, the process comprising:

forming a ridge structure in a layer of a first material, said layer having a first refractive index;

depositing a core layer over the ridge structure to form an intermediate structure, the core layer comprising a core material having a second refractive index;

depositing an upper cladding layer over the intermediate structure, the upper cladding layer comprising an upper cladding material having a third refractive index;

wherein the second refractive index is greater than the first refractive index and greater than the third refractive index, and wherein the process excludes a separate step of etching patterning the core layer,

wherein depositing the core layer is comprises depositing the core layer by a physical vapor deposition process, wherein the ridge structure is positioned opposite a central region of a target, wherein the target comprises the central region and outer regions, the central region comprising the core material and the outer regions comprising material of lower refractive index than the core material, and wherein radio frequency power is applied to the target in the presence of a gas such that a uniform plasma condition is created

in the vicinity of the target, sputtering material from the target onto the ridge structure.

Claim 19 (Previously presented): The process of Claim 18 wherein depositing the core layer further comprises

applying radio frequency power to the ridge structure.

Claim 20 (Original): The process of Claim 18 wherein the ridge structure comprises a ridge portion and a planar portion and the core layer comprises a core portion disposed overlying the ridge portion, a slab portion overlying the planar portion, and a sidewall portion disposed on a sidewall of the ridge portion, and wherein the sidewall portion comprises material of the outer regions of the target.

Claim 21(Withdrawn): The process of Claim 14 wherein depositing the core layer is depositing the core layer by a physical vapor deposition process wherein the ridge structure is positioned opposite a target composed of a target material and pulsed direct current power is applied to the target in the presence of a background gas and a reactive gas, wherein reaction between the target material and the reactive gas results in deposition of the core material onto the ridge structure.

Claim 22 (Withdrawn): The process of Claim 21 wherein the target material comprises aluminum and the reactive gas comprises oxygen.

Claim 23 (Withdrawn): The process of Claim 22 wherein the target material further comprises

a chemical species selected from the group consisting of silicon, rare earth elements, transition metal elements, and combinations thereof.

Claim 24 (Currently amended): The process of Claim 14 wherein depositing the upper cladding layer is comprises

depositing the upper cladding layer by a physical vapor deposition process wherein the intermediate structure is positioned opposite a cladding target composed of the upper cladding material and radio frequency power is applied to the cladding target in the presence of a gas such that a uniform plasma condition is created in the vicinity of the target, sputtering material from the cladding target onto the intermediate structure.

Claim 25 (Currently amended): The process of Claim 24 wherein depositing the upper cladding layer further comprises
applying radio frequency power to the intermediate structure.

Claim 26 (Original): The process of Claim 14 wherein the layer of core material has an average surface roughness of less than about 3 nanometers.

Claim 27 (Currently amended): The process of Claim 14 wherein forming the ridge structure in the layer of the first material comprises:
etching the ridge structure in a silicon wafer underlying the layer of the first material; and
exposing the etched silicon wafer to an oxidizing atmosphere under conditions wherein a portion of silicon of the silicon wafer undergoes a reaction to convert at least the ridge structure to a silica ridge structure on the silicon wafer.

Claim 28 (Withdrawn): The process of Claim 14 wherein depositing the core layer over the ridge structure comprises:
depositing a layer of a core host material over the ridge structure;
implanting ions of chemical species selected from the group consisting of rare earth ions, transition metal ions, and combinations thereof into the core host material to form core material.

Claim 29 (Currently amended): A method of fabricating a planar optical device, the method comprising:

forming a ridge structure in a layer of a first cladding material;
forming an intermediate structure by depositing core material overlying the ridge structure by a physical vapor deposition process in which, in the presence of a background gas, a first radio frequency power is applied to a sputtering target comprising the core material and a second radio frequency power is applied to the ridge structure; and depositing an upper cladding layer over the intermediate structure, the upper cladding layer comprising a second cladding material, wherein

the refractive index of the core material is greater than the refractive index of the first cladding material and of the second cladding material, and wherein the method excludes a separate step of etching patterning the core material.